AN77xxSP Series

3-pin, positive output, low dropout voltage regulator (1.2 A type)

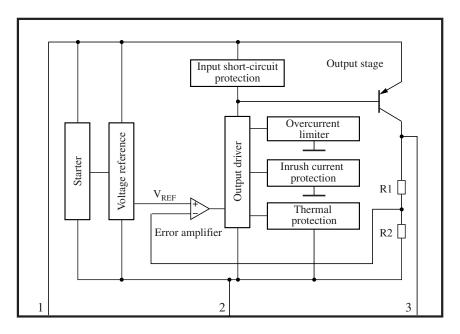
Overview

The AN77xxSP series is stabilized constant-voltage power supplies with small difference between I/O voltages (0.5 V typ.). It is suitable for low-voltage, battery-driven equipment, and home appliances and industrial equipment with great fluctuation of the supply voltage.

The output voltage ranges: 3.3 V, 5 V, 7 V, 9 V and 12 V

- Features
- Minimum I/O voltage difference: 0.5 V typ.
- On-chip overcurrent limiter
- On-chip thermal protection circuit
- On-chip inrush current protection circuit at the time of input voltage start-up
- On-chip input short-circuit protection circuit (When the input pin is short-circuited to the ground, the circuit between pins 1 and 3 is shut down to prevent current flow.)
- Applications
- Power supply equipment

Block Diagram



Pin Descriptions

Pin No.	Description
1	Input pin (In)
2	Ground pin (COM)
3	Output pin (Out)

Absolute Maximum Ratings at $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Supply voltage *2	V _{IN}	30	V
Supply current *3	I _{IN}	2.4	А
Power dissipation *4	P _D	5.0	W
Operating ambient temperature *1	T _{opr}	-30 to +85	°C
Storage temperature *1	T _{stg}	-55 to +150	°C

Note) *1: Expect for the operating ambient temperature and storage temperature, all ratings are for $T_a = 25^{\circ}C$.

*2: At the application of V_{IN} = 30 V, the overvoltage protection may be operated by the ASO protection circuit, leading to the output shut down.

*3: The current value does not exceed this criterion because of the on-chip current limiter.

*4: The internal circuit shuts off the output when $T_j \ge 150^{\circ}C$ (designed value). The relationship between the IC power dissipation and ambient temperature shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

Part No.	Output voltage	Operating supply voltage range (V_{IN})	Unit
AN77033SP	3.3	4.3 to 14	V
AN7705SP	5	6 to 16	V
AN7707SP	7	8 to 18	V
AN7709SP	9	10 to 20	V
AN7712SP	12	13 to 23	V

I Recommended Operating Conditions at $I_{OUT} = 500$ mA, $T_a = 25^{\circ}C$

Electrical Characteristics at $T_a = 25^{\circ}C$

• AN77033SP (3.3 V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V _{OUT}	$V_{IN} = 4.3 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	3.20	3.30	3.40	V
Line regulation	REG _{IN}	$V_{IN} = 4.3 V \text{ to } 14.3 V,$ $I_{OUT} = 500 \text{ mA}, T_j = 25^{\circ}\text{C}$	_	3	35	mV
Load regulation	REG _{LOA}	$V_{IN} = 4.3 \text{ V},$ $I_{OUT} = 0 \text{ mA to } 1200 \text{ mA}, \text{T}_{j} = 25^{\circ}\text{C}$		15	70	mV
Input dependency of bias current	$\Delta I_{Bias(IN)}$	$V_{IN} = 4.3 V \text{ to } 14.3 V,$ $I_{OUT} = 500 \text{ mA}, T_j = 25^{\circ}\text{C}$		1	10	mA
Load dependency of bias current	$\Delta I_{Bias(LOA)}$	$V_{IN} = 4.3 V,$ $I_{OUT} = 0 \text{ mA to } 1200 \text{ mA}, T_j = 25^{\circ}\text{C}$		10	50	mA
Bias current at no load	I _{Bias}	$V_{IN} = 4.3 \text{ V}, I_{OUT} = 0 \text{ mA}$		2.6	5.0	mA
Bias current before the regulation starts	I _{rush}	$V_{IN} = 3.0 \text{ V}, I_{OUT} = 0 \text{ mA}$		3	5	mA
Minimum I/O voltage difference 1	V _{DIF(min)1}	$V_{IN} = 3.7 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.4	0.6	V
Minimum I/O voltage difference 2	V _{DIF(min)2}	$V_{IN} = 3.7 \text{ V}, I_{OUT} = 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.5	1.0	V
Peak output current 1 *	I _{O(Peak)1}	$V_{IN} = 4.3 \text{ V}, T_j = 25 \text{ °C}$	1.2	1.8	2.4	A
Ripple rejection ratio	RR	$V_{IN} = 4.3 V \text{ to } 8.0 V,$ $I_{OUT} = 100 \text{ mA}, \text{ f} = 120 \text{ Hz}$	53	74		dB

Note) *: This current exceeds $P_{D(max)}$ because it is a parameter during abnormal (overcurrent) operation. However, normally, it shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Peak output current 2 *	I _{O(Peak)2}	$V_{IN} = 13.3 \text{ V}, T_j = 25^{\circ}\text{C}$	—	1.5	—	A
Peak output current 3 *	I _{O(Peak)3}	$V_{IN} = 18.3 \text{ V}, T_j = 25^{\circ}\text{C}$	—	1.0	—	A
Output short-circuit current	I _{O(Short)}	V_{IN} = 30 V, T_j = 25°C The load is shorted.		10		mA
Thermal protection operating temperature	T _{j(TH)}	V _{IN} = 4.3 V		150		°C
Output voltage temperature coefficient	a	$V_{IN} = 4.3 \text{ V}, T_j = 25^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		-40	_	ppm/°C

■ Electrical Characteristics at T_a = 25°C (continued)

• AN7705SP (5 V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V _{OUT}	$V_{IN} = 6 V$, $I_{OUT} = 500 mA$, $T_j = 25^{\circ}C$	4.85	5.00	5.15	V
Line regulation	REG _{IN}	$V_{IN} = 6 V$ to 16 V, $I_{OUT} = 500 \text{ mA}$, $T_j = 25^{\circ}\text{C}$	—	5	50	mV
Load regulation	REG _{LOA}	$V_{IN} = 6 \text{ V}, I_{OUT} = 0 \text{ mA to } 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	—	25	100	mV
Input dependency of bias current	$\Delta I_{Bias(IN)}$	$V_{IN} = 6 V$ to 16 V, $I_{OUT} = 500 \text{ mA}$, $T_j = 25^{\circ}\text{C}$	—	1	10	mA
Load dependency of bias current	$\Delta I_{\text{Bias}(\text{LOA})}$	$V_{IN} = 6 V$, $I_{OUT} = 0 mA$ to 1200 mA, $T_j = 25^{\circ}C$		10	50	mA
Bias current at no load	I _{Bias}	$V_{IN} = 6 V, I_{OUT} = 0 mA$		2.6	5	mA
Bias current before the regulation starts	I _{rush}	$V_{IN} = 4.5 \text{ V}, I_{OUT} = 0 \text{ mA}$		3	5	mA
Minimum I/O voltage difference 1	V _{DIF(min)1}	$V_{IN} = 4.5 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.4	0.6	V
Minimum I/O voltage difference 2	V _{DIF(min)2}	$V_{IN} = 4.5 \text{ V}, I_{OUT} = 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.5	1.0	V
Peak output current 1 *	I _{O(Peak)1}	$V_{IN} = 6 V, T_j = 25^{\circ}C$	1.2	1.8	2.4	A
Ripple rejection ratio	RR	$\label{eq:VIN} \begin{split} V_{IN} &= 6 \ V \ to \ 8 \ V, \ I_{OUT} = 100 \ mA, \\ f &= 120 \ Hz \end{split}$	50	70		dB

Note) *: This current exceeds $P_{D(max)}$ because it is a parameter during abnormal (overcurrent) operation. However, normally, it shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Peak output current 2 *	I _{O(Peak)2}	$V_{IN} = 15 \text{ V}, T_j = 25^{\circ}\text{C}$		1.5		A
Peak output current 3 *	I _{O(Peak)3}	$V_{IN} = 20 V, T_j = 25^{\circ}C$		1.0		А
Output short-circuit current	I _{O(Short)}	$V_{IN} = 30 V, T_j = 25^{\circ}C$ The load is shorted.		10		mA
Thermal protection operating temperature	T _{j(TH)}	$V_{IN} = 6 V$		150	_	°C
Output voltage temperature coefficient	a	$V_{IN} = 6 V, T_j = 25^{\circ}C \text{ to } 125^{\circ}C$		-40		ppm/°C

- Electrical Characteristics at $T_a = 25^{\circ}C$ (continued)
- AN7707SP (7 V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V _{OUT}	$V_{IN} = 8 V, I_{OUT} = 500 mA,$ $T_j = 25^{\circ}C$	6.79	7.00	7.21	V
Line regulation	REG _{IN}	$V_{IN} = 8 V$ to 18 V, $I_{OUT} = 500 \text{ mA}$, $T_j = 25^{\circ}\text{C}$		7	70	mV
Load regulation	REG _{LOA}	$V_{IN} = 8 \text{ V}, I_{OUT} = 0 \text{ mA to } 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		35	140	mV
Input dependency of bias current	$\Delta I_{Bias(IN)}$	$V_{IN} = 8 V$ to 18 V, $I_{OUT} = 500 \text{ mA}$, $T_j = 25^{\circ}\text{C}$	_	1	10	mA
Load dependency of bias current	$\Delta I_{\text{Bias(LOA)}}$	$V_{IN} = 8 V$, $I_{OUT} = 0 mA$ to 1200 mA, $T_j = 25^{\circ}C$		10	50	mA
Bias current at no load	I _{Bias}	$V_{IN} = 8 V, I_{OUT} = 0 mA$		2.6	5.0	mA
Bias current before the regulation starts	I _{rush}	$V_{IN} = 6.3 \text{ V}, I_{OUT} = 0 \text{ mA}$	_	3	5	mA
Minimum I/O voltage difference 1	V _{DIF(min)1}	$V_{IN} = 6.3 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.4	0.6	V
Minimum I/O voltage difference 2	V _{DIF(min)2}	$V_{IN} = 6.3 \text{ V}, I_{OUT} = 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.5	1.0	V
Peak output current 1 *	I _{O(Peak)1}	$V_{IN} = 8 V, T_j = 25^{\circ}C$	1.2	1.8	2.4	A
Ripple rejection ratio	RR	$V_{IN} = 8 V$ to 10 V, $I_{OUT} = 100 mA$, f = 120 Hz	47	67		dB

Note) *: This current exceeds $P_{D(max)}$ because it is a parameter during abnormal (overcurrent) operation. However, normally, it shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Peak output current 2 *	I _{O(Peak)2}	$V_{IN} = 17 \text{ V}, T_j = 25^{\circ}\text{C}$		1.5		Α
Peak output current 3 *	I _{O(Peak)3}	$V_{IN} = 22 V, T_j = 25^{\circ}C$		1.0		A
Output short-circuit current	I _{O(Short)}	$V_{IN} = 30 V, T_j = 25^{\circ}C$ The load is shorted.		10		mA
Thermal protection operating temperature	T _{j(TH)}	$V_{IN} = 8 V$	_	150	—	°C
Output voltage temperature coefficient	a	$V_{IN} = 8 V, T_j = 25^{\circ}C \text{ to } 125^{\circ}C$		-40		ppm/°C

■ Electrical Characteristics at T_a = 25°C (continued)

• AN7709SP (9 V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V _{OUT}	$V_{IN} = 10 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	8.73	9.00	9.27	V
Line regulation	REG _{IN}	$V_{IN} = 10 \text{ V to } 20 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	—	9	90	mV
Load regulation	REG _{LOA}	$V_{IN} = 10 V$, $I_{OUT} = 0 \text{ mA to } 1200 \text{ mA}$, $T_j = 25^{\circ}\text{C}$	_	45	180	mV
Input dependency of bias current	$\Delta I_{Bias(IN)}$	$V_{IN} = 10 \text{ V to } 20 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	—	1	10	mA
Load dependency of bias current	$\Delta I_{\text{Bias(LOA)}}$	$V_{IN} = 10 V$, $I_{OUT} = 0 mA$ to 1200 mA, $T_j = 25^{\circ}C$		10	50	mA
Bias current at no load	I _{Bias}	$V_{IN} = 10 \text{ V}, I_{OUT} = 0 \text{ mA}$		2.6	5.0	mA
Bias current before the regulation starts	I _{rush}	$V_{IN} = 8.1 \text{ V}, I_{OUT} = 0 \text{ mA}$	_	3	5	mA
Minimum I/O voltage difference 1	V _{DIF(min)1}	$V_{IN} = 8.1 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.4	0.6	V
Minimum I/O voltage difference 2	V _{DIF(min)2}	$V_{IN} = 8.1 \text{ V}, I_{OUT} = 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.5	1.0	V
Peak output current 1 *	I _{O(Peak)1}	$V_{IN} = 10 \text{ V}, \text{T}_{j} = 25^{\circ}\text{C}$	1.2	1.8	2.4	A
Ripple rejection ratio	RR	$V_{IN} = 10$ V to 12 V, $I_{OUT} = 100$ mA, f = 120 Hz	45	65		dB

Note) *: This current exceeds $P_{D(max)}$ because it is a parameter during abnormal (overcurrent) operation. However, normally, it shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Peak output current 2 *	I _{O(Peak)2}	$V_{IN} = 19 \text{ V}, T_j = 25^{\circ}\text{C}$		1.5		A
Peak output current 3 *	I _{O(Peak)3}	$V_{IN} = 24 \text{ V}, T_j = 25^{\circ}\text{C}$		1.0		Α
Output short-circuit current	I _{O(Short)}	$V_{IN} = 30 V, T_j = 25^{\circ}C$ The load is shorted.		10	_	mA
Thermal protection operating temperature	T _{j(TH)}	$V_{IN} = 10 V$		150	_	°C
Output voltage temperature coefficient	а	$V_{IN} = 10 \text{ V}, \text{T}_{j} = 25^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		-40		ppm/°C

■ Electrical Characteristics at T_a = 25°C (continued)

• AN7712SP (12 V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V _{OUT}	$V_{IN} = 13 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$	11.64	12.00	12.36	V
Line regulation	REG _{IN}	$V_{IN} = 13$ V to 23 V, $I_{OUT} = 500$ mA, $T_j = 25^{\circ}C$	_	12	120	mV
Load regulation	REG _{LOA}	$V_{IN} = 13 V,$ $I_{OUT} = 0 \text{ mA to } 1200 \text{ mA}, T_j = 25^{\circ}\text{C}$		60	240	mV
Input dependency of bias current	$\Delta I_{Bias(IN)}$	$V_{IN} = 13$ V to 23 V, $I_{OUT} = 500$ mA, $T_j = 25^{\circ}C$	—	1	10	mA
Load dependency of bias current	$\Delta I_{\text{Bias}(\text{LOA})}$	$V_{IN} = 13 \text{ V},$ $I_{OUT} = 0 \text{ mA to } 1200 \text{ mA}, T_j = 25^{\circ}\text{C}$		10	50	mA
Bias current at no load	I _{Bias}	$V_{IN} = 13 \text{ V}, I_{OUT} = 0 \text{ mA}$	_	2.6	5.0	mA
Bias current before the regulation starts	I _{rush}	$V_{IN} = 10.8 \text{ V}, I_{OUT} = 0 \text{ mA}$		3	5	mA
Minimum I/O voltage difference 1	V _{DIF(min)1}	$V_{IN} = 10.8 \text{ V}, I_{OUT} = 500 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.4	0.6	V
Minimum I/O voltage difference 2	V _{DIF(min)2}	$V_{IN} = 10.8 \text{ V}, I_{OUT} = 1200 \text{ mA},$ $T_j = 25^{\circ}\text{C}$		0.5	1.0	V
Peak output current 1 *	I _{O(Peak)1}	$V_{IN} = 13 \text{ V}, T_j = 25^{\circ}\text{C}$	1.2	1.8	2.4	А
Ripple rejection ratio	RR	$V_{IN} = 13$ V to 15 V, $I_{OUT} = 100$ mA, $f = 120$ Hz	42	62		dB

Note) *: This current exceeds $P_{D(max)}$ because it is a parameter during abnormal (overcurrent) operation. However, normally, it shall conform to the derating curve (\blacksquare Main Characteristics $P_D - T_a$).

• Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Peak output current 2 *	I _{O(Peak)2}	$V_{IN} = 22 V, T_j = 25^{\circ}C$		1.5		Α
Peak output current 3 *	I _{O(Peak)3}	$V_{IN} = 27 \text{ V}, T_j = 25^{\circ}\text{C}$		1.0		A
Output short-circuit current	I _{O(Short)}	$V_{IN} = 30 \text{ V}, T_j = 25^{\circ}\text{C}$ The load is shorted.	—	10	—	mA
Thermal protection operating temperature	T _{j(TH)}	$V_{IN} = 13 V$		150	_	°C
Output voltage temperature coefficient	а	$V_{IN} = 13 \text{ V}, T_j = 25^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		-40		ppm/°C

1. Input short-circuit protection circuit

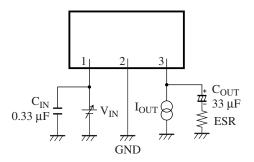
When the DC input pin (pin 1) and the ground pin (pin 2) of our conventional three-pin regulators (AN78xxNSP series, etc.) were short-circuited at normal use conditions in some cases, the voltage of the output pin (pin 3) becomes higher than that of the DC input pin and electrons charged in the output capacitor C_{OUT} flow into the input side, resulting in break of the element.

In those cases, it was necessary for you to connect a general silicon diode as shown in the figure on the right. In the AN77xxSP series, however, it is not necessary to connect the protection diode because these series have a built-in protection circuit to safeguard the element from discharge current.

2. Capacitor for external compensation

To maintain the stability, insert a 33 mF capacitor as close to pin 3 and pin 2 as possible. In case of using at low temperature, decrease in capacity of the aluminum electrolytic capacitor and increase of ESR of this capacitor may lead to oscillation.

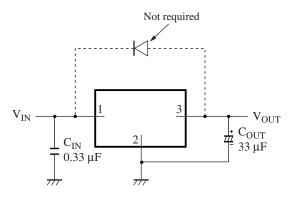
In the AN77xxSP series, for the output capacitor C_{OUT} , it is recommended to use an aluminum electrolytic capacitor or tantalum capacitor whose equivalent series resistance (ESR) has the temperature characteristic within the recommended area shown on the right.

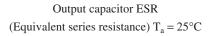


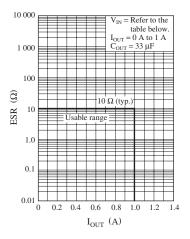
3. Others

Cautions for the input voltage that exceeds the operating supply voltage:

- 1) The overvoltage protection is activated with the ASO protection circuit when $V_{IN} = 30$ V is applied, and the output shuts down occasionally. (3 V type to 10 V type)
- Please note that at I_{OUT} < 2 mA, the output voltage rises and may exceed the maximum of the operation range. (12 V type to 24 V type)



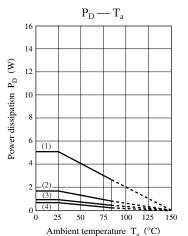


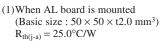


Part No.	V _{IN}
AN77033SP	4.3 V to 14 V
AN7705SP	6 V to 16 V
AN7707SP	8 V to 18 V
AN7709SP	10 V to 20 V
AN7712SP	13 V to 23 V

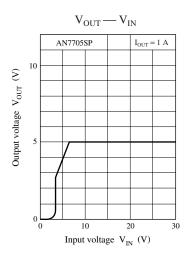
Panasoni

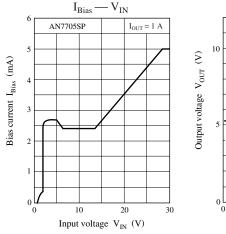
Main Characteristics

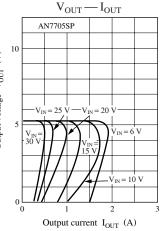


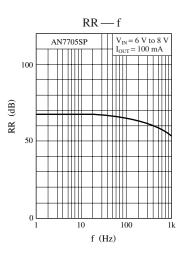


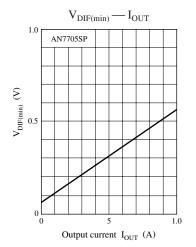
- (2) When glass epoxy is mounted 2 (Basic size : $50 \times 50 \times t1.5 \text{ mm}^3$) $R_{th(j-a)} = 89.3^{\circ}\text{C/W}$
- (3) When glass epoxy is mounted 1 (Basic size : $50 \times 50 \times t1.7 \text{ mm}^3$) $R_{\text{th}(j-a)} = 147.0^{\circ}\text{C/W}$
- (4) Without heat sink $R_{th(j-a)} = 178.0^{\circ}C/W$

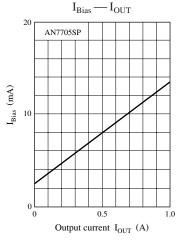


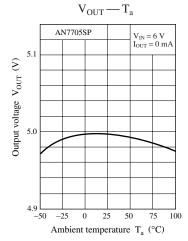




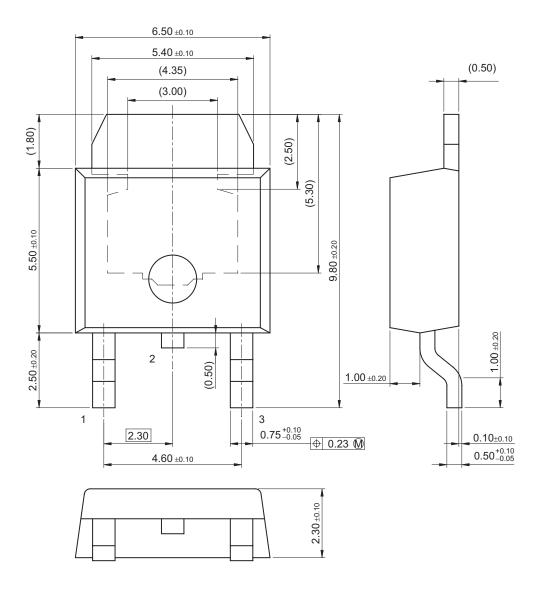








- Package Dimensions (Unit: mm)
- SP-3SUA



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- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.

Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
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